NSN 5961-01-412-7742

Diode Semiconductor Device - Page 1 of 1

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Inclosure Material:

Plastic

Overall Length:

4.6 millimeters

Overall Height:

4.25 millimeters

Overall Width:

1.6 millimeters

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

Sot-89

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

200.0 breakdown voltage, dc

Current Rating Per Characteristic:

50.00 microamperes reverse current, dc

Power Rating Per Characteristic:

1.0 watts total power dissipation

Capacitance Rating In Picofarads:

10.0

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Terminal Type And Quantity:

3 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0